

# Triple High-Voltage Scan Driver for TFT-LCD

Check for Samples: TPS65191

### **FEATURES**

- Triple High-Voltage Scan Driver
- Scan Driver Output Charge Share
- High Output-Voltage Level: Up to 35 V
- Low Output-Voltage Level: Down to -28 V
- Logic-Level Inputs

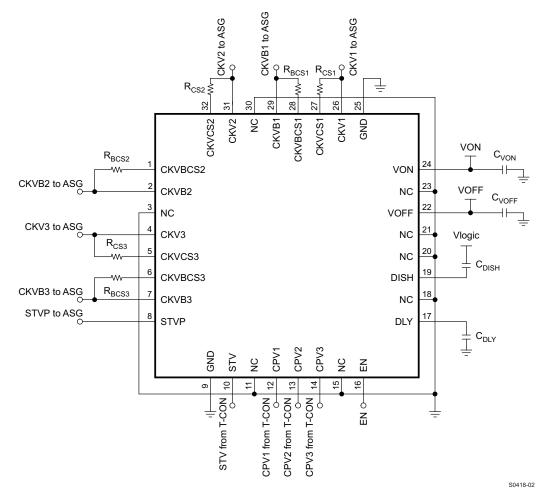
### 32-pin 5-mm × 5-mm QFN Package

## **APPLICATIONS**

 TFT LCD Using ASG (Amorphous Silicon Gate) Technology

#### **DESCRIPTION**

The TPS65191 is a triple high-voltage scan driver to drive an ASG (amorphous silicon gate) circuit on TFT glass. Each single high-voltage scan driver receives logic-level inputs of CPVx and generates two high-voltage outputs of CKVx, CKVBx. The device receives a logic-level input of STV and generates a high-voltage output of STVP. These outputs are swings from Voff (–28 V) to Von (35 V) and are used to drive the ASG circuit and charge/discharge the capacitive loads of the TFT LCD. In order to reduce the power dissipation of device, a charge-share function is implemented. The device features discharge function, which shorts Voff to GND in order to shut down the panel faster when the LCD is turned off.





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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### ORDERING INFORMATION<sup>(1)</sup>

T <sub>A</sub>	ORDERING P/N	PACKAGE	PACKAGE MARKING
-40°C to 85°C	TPS65191RHBR	32-pin 5-mm × 5-mm QFN	TPS65191

<sup>(1)</sup> The RHB package has quantities of 2500 devices per reel.

## ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

	VALUE	UNIT
Voltage on pins CPVx, STV	-0.3 to 5.5	V
Voltage on pins EN	-0.3 to 5.5	V
Input voltage on VON <sup>(2)</sup>	40	V
Input voltage on VOFF <sup>(2)</sup>	-30	V
Voltage on CKVx, CKVBx, CKVCSx, CKVBCSx	-30 to 40	V
VON-VOFF	62	V
Voltage on STVP	-30 to 40	V
Voltage on DISH	-3.6 to 5.5	V
ESD rating, HBM	2	kV
ESD rating, MM	200	V
ESD rating, CDM	700	V
Continuous power dissipation See Dissipa		ating Table
Operating junction temperature range	-40 to 150	°C
Storage temperature range	-65 to 150	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **DISSIPATION RATINGS**

PACKAGE	$R_{ hetaJA}$	T <sub>A</sub> ≤ 25°C POWER RATING	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
32-pin 5-mm × 5-mm QFN	75°C/W (Low-K board)	1.33 W	0.73 W	0.53 W

#### RECOMMENDED OPERATING CONDITIONS

		MIN	TYP	MAX	UNIT
VON	Positive high-voltage range	15		35	V
VOFF	Negative low-voltage range	-28		-3	V
VON-VOFF	VON to VOFF voltage range			60	V
$f_{CPV}$	CPV input frequency			150	kHz
T <sub>A</sub>	Operating ambient temperature	-40		85	°C
TJ	Operating junction temperature	-40		125	°C

Product Folder Link(s): TPS65191

<sup>(2)</sup> All voltage values are with respect to network ground terminal.



## **ELECTRICAL CHARACTERISTICS**

VOFF = -10 V, VON = 30 V, EN = 3.3 V,  $T_A = -40$ °C to 85°C, typical values are at  $T_A = 25$ °C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY	CURRENT				''	
	Quiescent current into VON	OFILE ONE OTHER		600	900	
I <sub>QIN</sub>	Quiescent current out of VOFF	$\Box$ CPVx = GND, STV = 3.3 V		120	200	μΑ
	Shutdown current into VON	CPVx = GND, STV = 3.3 V,		520	900	
I <sub>SD</sub>	Shutdown current out of VOFF	EN = GND		260	400	μА
UNDERV	OLTAGE LOCKOUT					
V <sub>LIVLO</sub> Undervoltage lockout threshold on VON		VON rising	10		13	V
$V_{UVLO}$	Ondervoltage lockout threshold on VON	Hysteresis		250		mV
LOGIC S	IGNALS EN, CPVx, STV					
V <sub>IH</sub>	High level input voltage of CPVx, STV, EN		2			V
$V_{IL}$	Low level input voltage of CPVx, STV, EN				0.5	V
OUTPUT	CKVx, CKVBx, STVP, CKVCSx				·	
\/	Output high voltage of CKVx, CKVBx	1 10 m/s	VON - 0.3			V
$V_{OH}$	Output high voltage of STVP	I <sub>OH</sub> = 10 mA	VON - 0.8			V
\/	Output low voltage of CKVx, CKVBx	10 m/		V	OFF + 0.2	V
$V_{OL}$	Output low voltage of STVP	$I_{OL} = -10 \text{ mA}$	VOFF + 0.4		OFF + 0.4	V
R <sub>CHSH</sub>	Charge sharing on resistance	I <sub>CHSH</sub> = 10 mA		120		Ω
DISCHAF	RGING CIRCUIT					-
R <sub>DSCHG</sub>	Discharging resistance	DISH = -2 V		1.5		kΩ
R <sub>BIAS</sub>	Resistance DISH to GND			100		kΩ
CONTRO	DL DELAY					-
V <sub>DLYREF</sub>	Reference voltage for comparator			2.9		V
I <sub>DLYREF</sub>	Delay charge current			15		μΑ
R <sub>DLY</sub>	Delay resistor		140	200	260	kΩ

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# **ELECTRICAL CHARACTERISTICS (continued)**

VOFF = -10 V, VON = 30 V, EN = 3.3 V,  $T_A = -40$ °C to 85°C, typical values are at  $T_A = 25$ °C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
AC CHA	RACTERISTICS	1201 GONDINGNO			IIII UX	<u> </u>
Slew-	Slew rate, Slew- STVP		30	55		V/μs
Slew+	Slew rate, Slew+ STVP	Lood 47 pF (Coo Figure 4)	20	35		V/μs
t <sub>pf</sub>	Propagation delay, t <sub>pf-STVP</sub>	Load = 4.7 nF (See Figure 1)		40	100	ns
t <sub>pr</sub>	Propagation delay, t <sub>pr-STVP</sub>			30	100	ns

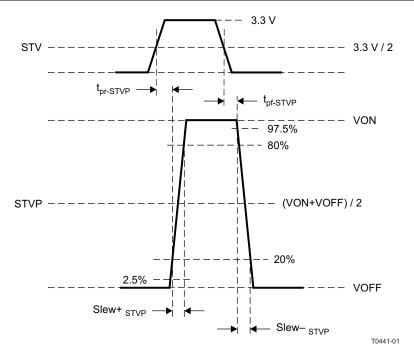


Figure 1. Switching Characteristics of STVP



## CKVx, CKVBx SWITCHING CHARACTERISTICS

 $VOFF = -10 \text{ V}, \text{ VON} = 30 \text{ V}, \text{ EN} = 3.3 \text{ V}, \text{ T}_{A} = -40 ^{\circ}\text{C to } 85 ^{\circ}\text{C}, \text{ typical values are at } \text{T}_{A} = 25 ^{\circ}\text{C (unless otherwise noted)}$ 

	**					-
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>csf</sub>	t <sub>csf-CPVx_CKVx</sub> , t <sub>csf-CPVx_CKVBx</sub>			80	150	ns
t <sub>csr</sub>	t <sub>csr-CPVx_CKVx</sub> , t <sub>csr-CPVx_CKVBx</sub>	$f_{CPVx} = 85 \text{ kHz}, STV = GND,$		80	150	ns
t <sub>f</sub>	t <sub>f-CPVx_CKVx</sub> , t <sub>f-CPVx_CKVBx</sub>	See Figure 2, load = 4.7 nF, $R_{CS1} = R_{BCS1} = R_{CS2} = R_{BCS2} = 50 \Omega$		40	100	ns
t <sub>r</sub>	t <sub>r-CPVx_CKVx</sub> , t <sub>r-CPVx_CKVBx</sub>	33. 332 332		30	100	ns

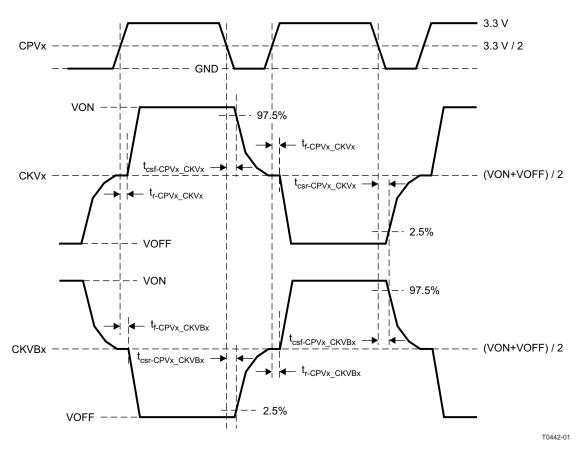


Figure 2. Switching Characteristics of CKVx, CKVBx (STV = GND)

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# CKVx, CKVBx SWITCHING CHARACTERISTICS (Continued)

VOFF = -10 V, VON = 30 V, EN = 3.3 V,  $T_A = -40 ^{\circ}\text{C}$  to  $85 ^{\circ}\text{C}$ , typical values are at  $T_A = 25 ^{\circ}\text{C}$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Slew+	Slew+ <sub>CKVx</sub> , Slew+ <sub>CKVBx</sub>	$f_{CPVx}$ = 85 kHz, STV = 3.3 V, See Figure 3, load = 4.7 nF, $R_{CSx}$ = $R_{BCSx}$ = 50 $\Omega$	50	100		V/μs
Slew-	Slew- <sub>CKVx</sub> , Slew- <sub>CKVBx</sub>	$f_{CPVx} = 85 \text{ kHz}, STV = 3.3 \text{ V}, See Figure 3, load = 4.7 nF, R_{CSx} = R_{BCSx} = 50 \Omega$	70	130		V/μs

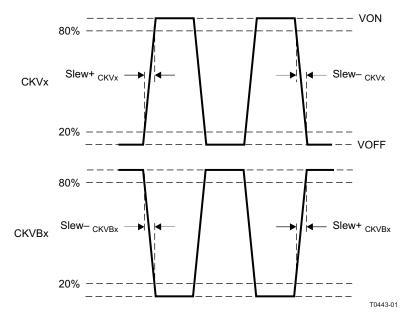


Figure 3. CKVx, CKVBx Output Rise and Fall Times (STV = 3.3 V)



### **DEVICE INFORMATION**

#### **RHB Package** (Top View) VOFF DLY 23 22 21 20 19 18 **GND** ΕN CKV1 NC \_)26 CKVCS1 \_)27 CPV3 CKVBCS1 Exposed Thermal Pad \_) 28 CPV2 CKVB1 -) 29 CPV1 NC NC \_\_\_\_30 CKV2 10( STV \_)31 CKVCS2 GND 6 CKVB2 CKV3 CKVB3 STVP CKVBCS2 2 **CKVCS3** CKVBCS3 P0048-13

Exposed thermal pad and NC pins are recommended to be connected with ground on the PCB for better thermal dissipation.

#### PIN FUNCTIONS

PIN	I	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
CKV1	26	0	Output vertical-scan clock 1 for ASG
CKV2	31	0	Output vertical-scan clock 2 for ASG
CKV3	4	0	Output vertical-scan clock 3 for ASG
CKVB1	29	0	Inverted-output vertical-scan clock 1 for ASG
CKVB2	2	0	Inverted-output vertical-scan clock 2 for ASG
CKVB3	7	0	Inverted-output vertical-scan clock 3 for ASG
CKVBCS1	28	I	Charge-share input for CKVB1
CKVBCS2	1	I	Charge-share input for CKVB2
CKVBCS3	6	I	Charge-share input for CKVB3
CKVCS1	27	I	Charge-share input for CKV1
CKVCS2	32	I	Charge-share input for CKV2
CKVCS3	5	I	Charge-share input for CKV3
CPV1	12	I	Input vertical-scan clock 1
CPV2	13	I	Input vertical-scan clock 2
CPV3	14	I	Input vertical-scan clock 3
DISH	19	I	VOFF discharge control
DLY	17	0	Connecting a capacitor from this pin to GND allows the setting of the start-up delay.
EN	16	I	Enable pin of device. When this pin is pulled high, the device starts up after a delay time set by DLY has passed.
GND	9, 25	-	Ground
NC	3, 11, 15, 18, 20, 21, 23, 30	_	Not connected

Product Folder Link(s): TPS65191



## **PIN FUNCTIONS (continued)**

PIN		1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
STV	10	I	Input vertical-scan start signal
STVP	8	0	Output vertical-scan start signal
VOFF	22	I	Negative low-supply voltage
VON	24	I	Positive high-supply voltage
Thermal pad		_	Not connected

## TYPICAL CHARACTERISTICS

### **TABLE OF GRAPHS**

		FIGURE
YSTEM PERFORMANCE		<u> </u>
Start-up sequence CKVx	EN = HIGH after UVLO, C <sub>DLY</sub> = 10 nF, STV = LOW	Figure 4
	EN = HIGH before UVLO, C <sub>DLY</sub> = 10 nF, STV = LOW	Figure 5
Start-up sequence STVP	EN = HIGH after UVLO, C <sub>DLY</sub> = 10 nF, CPVx = LOW	Figure 6
	EN = HIGH before UVLO, C <sub>DLY</sub> = 10 nF, CPVx = LOW	Figure 7
UTPUT CKVx, CKVBx and STVP		
Rise time / propagation delay of CKVx	STV = HIGH, load = 4.7 nF	Figure 8
	STV = LOW, load = 4.7 nF	Figure 9
Fall time / propagation delay of CKVx	STV = HIGH, load = 4.7 nF	Figure 10
	STV = LOW, load = 4.7 nF	Figure 11
Rise time / propagation delay of STVP	CPV1 = LOW, load = 4.7 nF	Figure 12
Fall time / propagation delay of STVP	CPV1 = LOW, load = 4.7 nF	Figure 13
STVP output	CPV1 = HIGH	Figure 14
	CPV1 = LOW	Figure 15
CKVx, CKVBx outputs	STV = HIGH	Figure 16
	STV = LOW	Figure 17

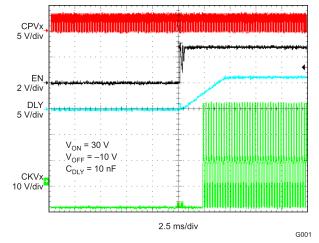


Figure 4. Start-Up Sequence CKVx, EN = HIGH After UVLO

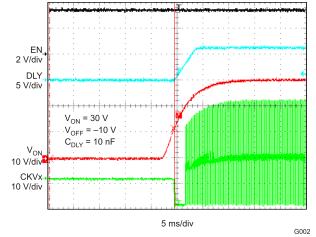
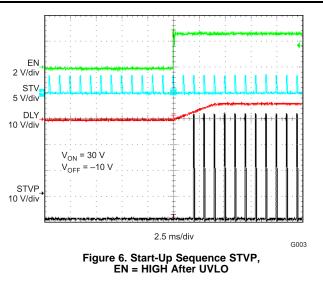


Figure 5. Start-Up Sequence CKVx, EN = HIGH Before UVLO





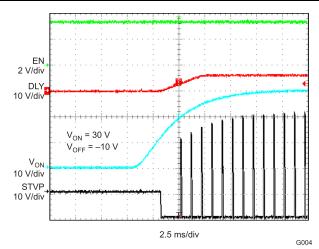
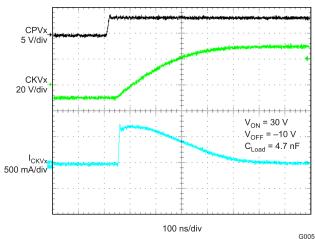


Figure 7. \Start-Up Sequence STVP, EN = HIGH Before UVLO



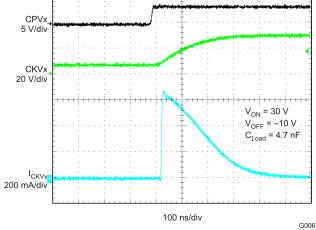
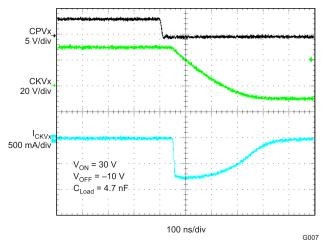


Figure 8. Rise Time / Propagation Delay of CKVx, STV = HIGH

Figure 9. Rise Time / Propagation Delay of CKVx, STV = LOW



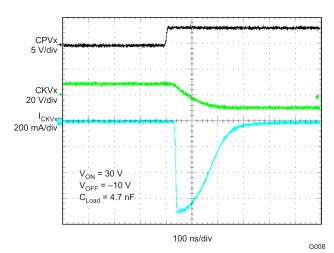


Figure 10. Fall Time / Propagation Delay of CKVx, STV = HIGH

Figure 11. Fall Time / Propagation Delay of CKVx, STV = LOW



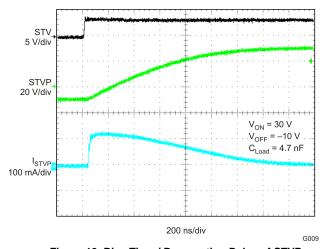


Figure 12. Rise Time / Propagation Delay of STVP, CPV1 = LOW

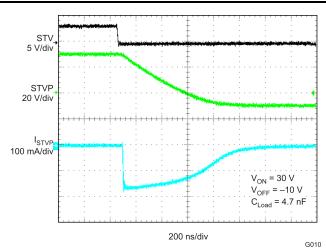


Figure 13. Fall Time / Propagation Delay of STVP, CPV1 = LOW

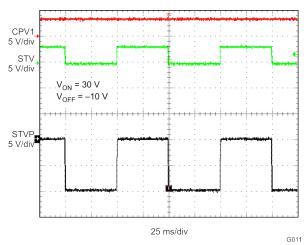


Figure 14. STVP Output, CPV1 = HIGH

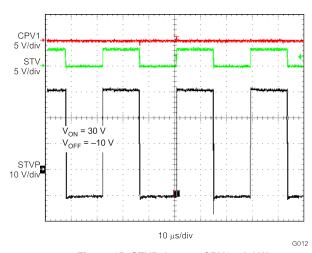


Figure 15. STVP Output, CPV1 = LOW

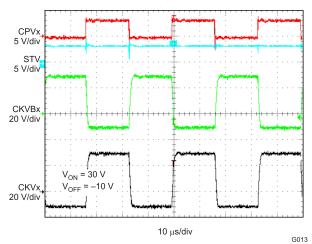


Figure 16. CKVx, CKVBx Outputs, STV = HIGH

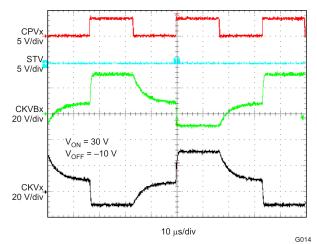
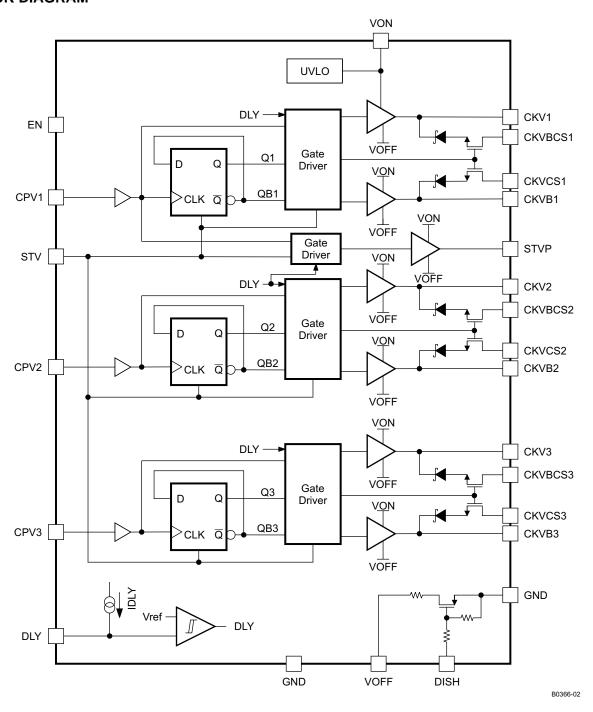


Figure 17. CKVx, CKVBx Outputs, STV = LOW



#### **BLOCK DIAGRAM**



### **DETAILED DESCRIPTION**

## **UNDERVOLTAGE LOCKOUT**

The device has an undervoltage lockout feature to avoid improper operation of the device when input voltage VON is low. When VON is lower than 10 V, the device shuts down, and outputs CKVx, CKVBx, and STVP enter the high-impedance state.

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#### **INPUT SIGNALS**

The timing controller in the system provides input signals of TPS65191. STV is the synchronous signal for picture frames, and its frequency depends on frame rate. CPVx are the synchronous signals for horizontal lines, and their frequency depends on frame rate and vertical resolution.

#### **OUTPUT SIGNALS**

The STVP, CKVx, and CKVBx of scan-driver outputs are generated with internal switches. Table 1 and Table 2 show the logic diagrams of the scan-driver outputs.

**Table 1. STVP Logic Diagram** 

INF	INPUT			
STV	CPV1	STVP		
LOW	Don't care	VOFF		
HIGH	LOW	VON		
HIGH	HIGH	High impedance		

Table 2. CKVx, CKVBx, and Output Charge-Share Logic

INF	TUT	OUTPUT				
STV	CPVx	CKVx	CKVBx	CHARGE SHARE		
LOW	LOW	High impedance	High impedance	Enable		
LOW	Rising edge	Toggle state	Toggle state	Disable		
LOW	HIGH	Previous state	Previous state	Disable		
HIGH	LOW	VOFF	VON	Disable		
HIGH	HIGH	VON	VOFF	Disable		

#### **OUTPUT CHARGE SHARE**

Power dissipation can be reduced by the output charge share. Figure 18 shows the current flows when the charge share is enabled. CKVCSx and CKVBCSx are charge-share inputs. When the charge share is enabled, the charge that is in the capacitor of the positive voltage line is transferred to the capacitor of the negative voltage line. Charge-sharing resistors  $R_{CSx}$  and  $R_{BCSx}$  reduce the peak current into charge-share inputs, CKVCSx and CKVBCSx, during the output charge share. These resistors also control the slope of the output charge-share waveform. The smaller  $R_{CSx}$  and  $R_{BCSx}$ , the higher the peak current into the charge-share inputs and the steeper the slope of output charge-share waveform. The power dissipation in charge-sharing resistors should be taken into consideration. With 0603 size resistors, the power rating of two in parallel is good for most applications.



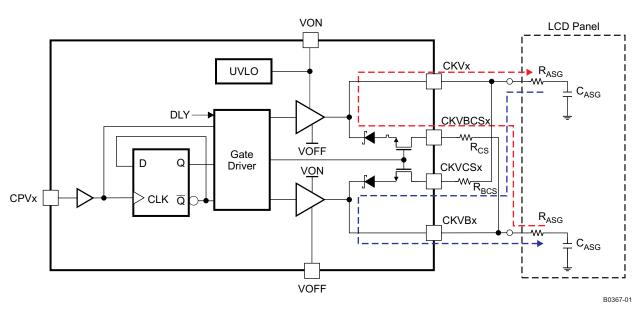


Figure 18. Single-Scan Driver Block Diagram

## START-UP SEQUENCE (EN, DLY)

The TPS65191 has an adjustable start-up sequencing that is set by EN and DLY. When VON is below the UVLO threshold, all outputs are at high impedance. When EN is pulled LOW after UVLO threshold is reached, all outputs follow VOFF. Pulling EN high enables the device after a delay time set by the capacitor connected to DLY, and the delay time starts when EN = HIGH. If EN is pulled high before the UVLO threshold is reached, the delay starts when VON reaches the UVLO threshold. Pulling EN low disables the device, and outputs CKVx, CKVBx, and STVP follow VOFF as long as VON is higher than the UVLO threshold. For the typical start-up sequence, see Figure 19 and Figure 20.

## **SETTING THE DELAY TIME (DLY)**

Connecting an external capacitor to the DLY pin sets the delay time. If no delay time is required, the DLY pin can be left floating. The external capacitor is charged with a constant-current source of typically 15  $\mu$ A. The delay time is terminated when the capacitor voltage reaches the internal reference voltage of 2.9 V, and the final DLY voltage on an external capacitor is maximum 8 V. The voltage rating of the external capacitor must be higher than 8 V.

The external delay capacitor is calculated using the following formula:

$$C_{DLY} = \frac{\text{Delay time}}{R_{DLY}} = \frac{\text{Delay time}}{200 \text{ k}\Omega} \tag{1}$$

Example for setting a delay time of 10 ms:

$$C_{DLY} = \frac{10 \text{ ms}}{200 \text{ k}\Omega} = 50 \text{ nF} \approx 47 \text{ nF}$$
 (2)

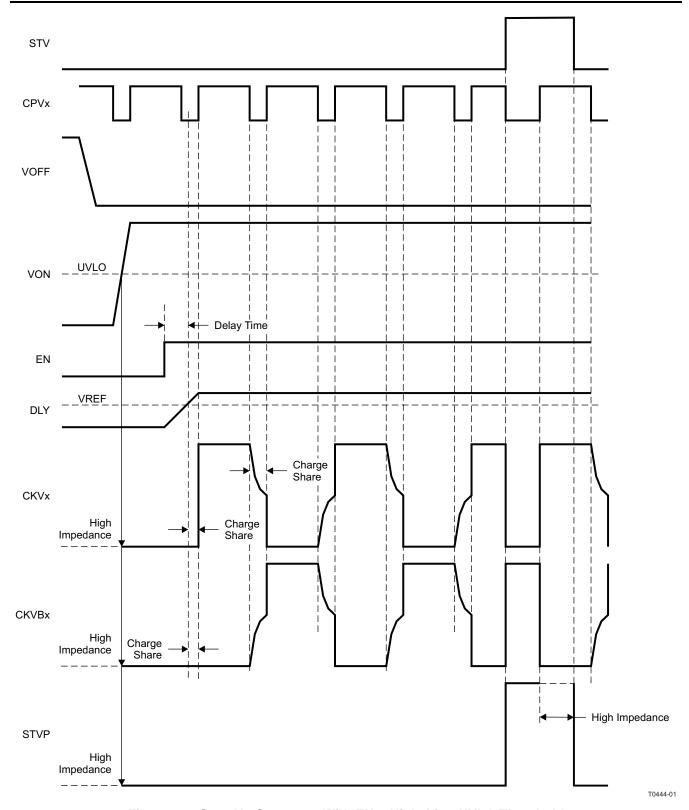


Figure 19. Start-Up Sequence With EN = High After UVLO Threshold



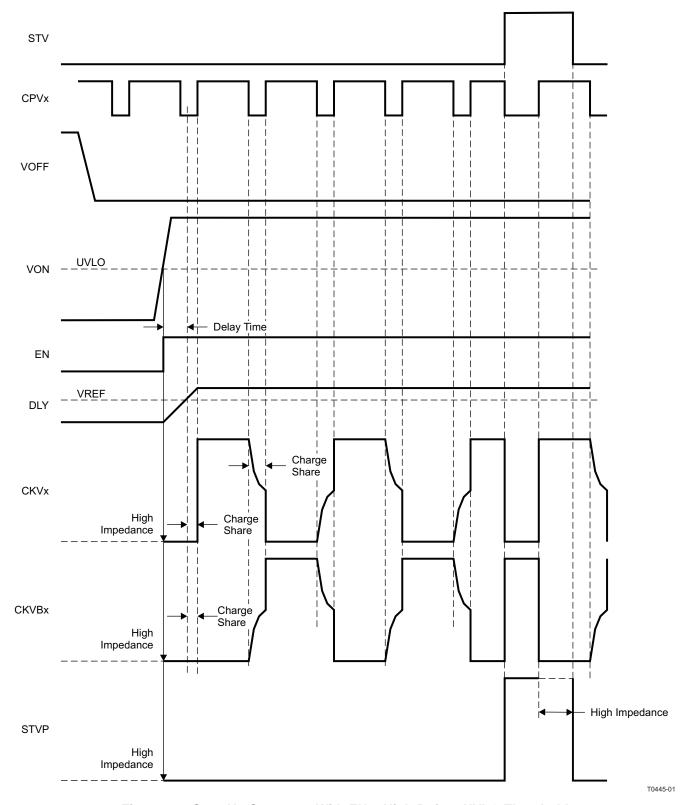


Figure 20. Start-Up Sequence With EN = High Before UVLO Threshold



#### TIMING DIAGRAM OF SCAN DRIVER

Figure 21 shows the typical timing diagram of the TPS65191.

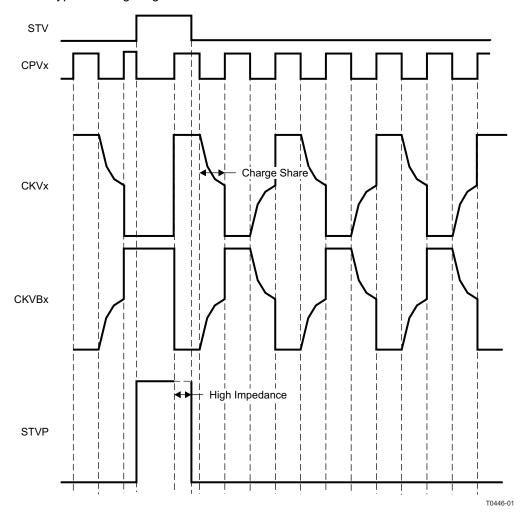


Figure 21. Scan Driver Timing Diagram

## **SUPPLY VOLTAGE VON and VOFF**

The TPS65191 drives the capacitive load. The high peak currents should be supplied from VON on the rising edges of the outputs and VOFF on the falling edges of the outputs, respectively. Bypass capacitors of 1  $\mu$ F must be placed as close as possible on both the VON and VOFF supplies. Depending on the peak current that the TPS65191 must deliver, the bypass capacitor can be bigger than 1  $\mu$ F.

#### **VOFF DISCHARGE**

DISH controls the VOFF discharging time during the system power off. Figure 22 shows a typical application for VOFF discharge. DISH is connected to the system logic voltage through a capacitor. During the power off, the system logic voltage falls, and the voltage on DISH falls below ground level. Internal switch turns on when DISH is below –0.6V and VOFF is connected to ground through  $1k\Omega$ , which helps VOFF discharge. A 1- $\mu$ F DISH capacitor is good for most applications. Figure 23 shows the typical power-off sequence of VOFF discharging. VOFF discharge can be disabled by connecting DISH to GND directly.



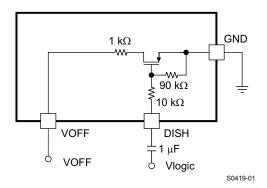


Figure 22. Typical Application for VOFF Discharge

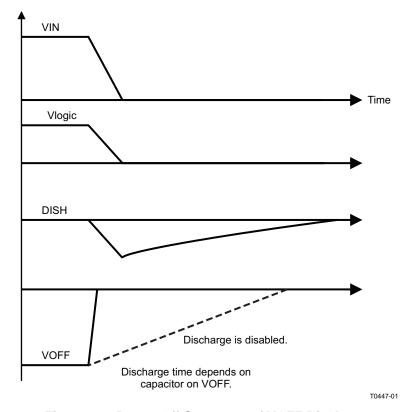


Figure 23. Power-Off Sequence of VOFF Discharge



### TYPICAL APPLICATION

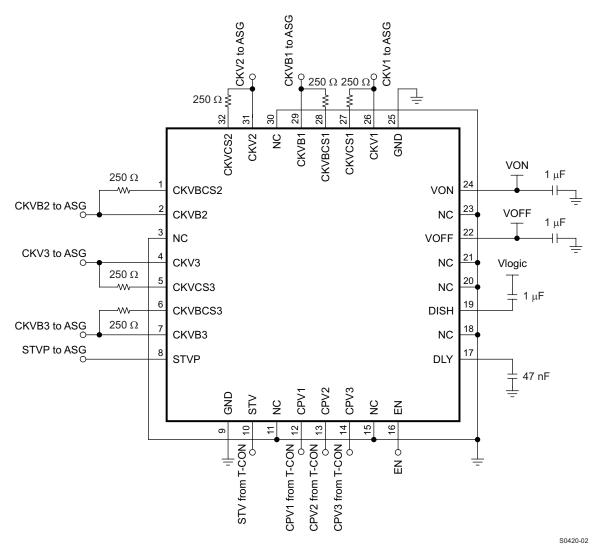


Figure 24. Typical Application With VOFF Discharge Enabled



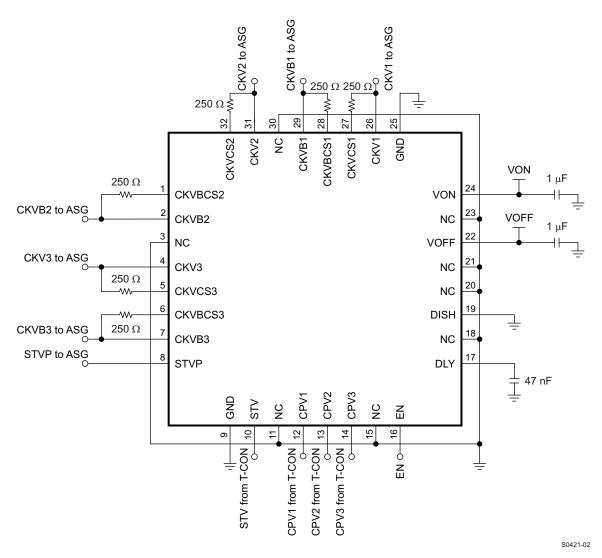


Figure 25. Typical Application With VOFF Discharge Disabled

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## **REVISION HISTORY**

Cł	Changes from Revision Original (July 2009) to Revision A							
•	Changed upper voltage limit from 37 V to 40 V in three places in the Abs Max Ratings table		2					



## PACKAGE OPTION ADDENDUM

1-May-2018

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS65191RHBR	NRND	VQFN	RHB	32	3000	Green (RoHS	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS	
						& no Sb/Br)				65191	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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5 x 5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4224745/A





PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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